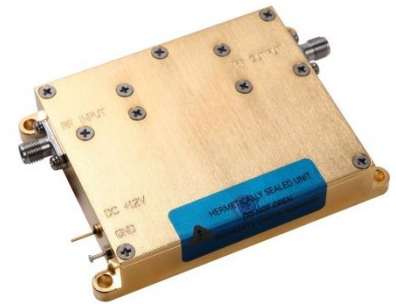


FEATURES

- Class AB GaAs design
- Instantaneous wide Bandwidth
- Suitable for all single channel modulation standards
- Built-in protection circuits
- High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	6.0 - 18.0 GHz	
Power Output Past	1.0 Watt Min	CW
Small Signal Gain	20 dB Min	
Power Gain Flatness	3 dB p-p Max	
Input / Output Return Loss	10 dB Max	
Harmonics	-20 dBc Max	At rated Pout
Noise Figure	5.0 dB Max	
3 rd Order Intercept	+34 dBm Typ	Design Goal
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	9.0 VDC \pm 0.2 V	
Current Consumption	1.5 Amp Max	At rated Pout
Max Input Power	+20 dBm Max	Without damage
Load VSWR	5 : 1 Max	

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +65 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non -condensation

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	70 x 60 x 15mm	Excluding connectors
Weight	300 gr.	
RF Connectors In/Out	SMA female	Cover Flange
DC Power / Interface Connector		
Cooling	External Heatsink	Forced air required

PIN ASSIGNMENT

Pin	Function	Description
1	DC Voltage	+9VDC
2	GND	GND

OUTLINE DRAWING

